

Circuit configuration

Vishay Semiconductors

Standard Recovery Diodes, Generation 2 DO-5 (Stud Version), 80 A

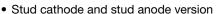


PRIMARY CHARACTERISTICS				
I _{F(AV)}	80 A			
Package	DO-5 (DO-203AB)			

Single

FEATURES

- High surge current capability
- · Designed for a wide range of applications



RoHS

- Wire version available
- Low thermal resistance
- · Designed and qualified for multiple level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- · Battery charges
- Converters
- · Power supplies
- · Machine tool controls
- Welding

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
1		80	Α	
I _{F(AV)}	T _C	123	°C	
I _{F(RMS)}		126	А	
I _{FSM}	50 Hz	1200	A	
	60 Hz	1250	A	
l²t	50 Hz	7100	A ² s	
	60 Hz	6450	A-S	
V _{RRM}	Range	1400 to 1600	V	
T _J		-55 to +150	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS						
TYPE NUMBER VOLTAGE CODE VRRM, MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V		V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 150 °C mA			
VS-80PF(R)(W)	140	1400	1650	4.5		
V3-60FF(h)(VV)	160	1600	1900	4.5		

VS-80PF(R)...(W) High Voltage Series

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FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current	l=	190° conduction half sine ways		180° conduction, half sine wave	80	Α
at case temperature	I _{F(AV)}	100 Conduc	ction, nan sine w	ave	123	°C
Maximum RMS forward current	I _{F(RMS)}				126	Α
Maximum peak, one-cycle forward, non-repetitive surge current		t = 10 ms	No voltage	Sinusoidal half wave, initial T _J = 150 °C	1200	А
	I _{FSM}	t = 8.3 ms	reapplied		1250	
		t = 10 ms	100 % V _{RRM}		1000	
		t = 8.3 ms	reapplied		1050	
	l ² t	t = 10 ms	No voltage		7100	A ² s
Maximum I ² t for fusing		t = 8.3 ms	reapplied		6450	
Maximum I-t for fusing		t = 10 ms	100 % V _{RRM}		5000	
		t = 8.3 ms	reapplied		4550	
Maximum I ² √t for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied		71 000	A²√s	
Low level value of threshold voltage	V _{F(TO)}	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), $T_J = T_J$ maximum		0.73	V	
Low level value of forward slope resistance	r _f	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		3.0	mΩ	
Maximum forward voltage drop	V_{FM}	l _{pk} = 220 A, T _J = 25 °C, t _p = 400 μs rectangular wave		1.46	V	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction operating and storage temperature range	T _J , T _{Stg}		-55 to 180	°C	
Maximum thermal resistance, junction to case	R _{thJC}	R _{thJC} DC operation		K/W	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25	r. vv	
Allowable mounting torque		Not lubricated threads, tighting on nut (1)	3.4 (30)		
		Lubricated threads, tighting on nut (1)	2.3 (20)	N⋅m	
		Not lubricated threads, tighting on Hexagon (2)	4.2 (37)	(lbf · in)	
		Lubricated threads, tighting on Hexagon (2)	3.2 (28)		
Approximate weight			15.8	g	
Approximate weight			0.56	OZ.	
Case style		See dimensions - link at the end of datasheet DO-5 (DO-203A)		O-203AB)	

Notes

⁽²⁾ Torque must be applicable only to Hexagon and not to plastic structure, recommended for holed heatsink

△R _{thJC} CONDUCTION					
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.14	0.10			
120°	0.16	0.17			
90°	0.21	0.22	$T_J = T_J$ maximum	K/W	
60°	0.30	0.31			
30°	0.50	0.50			

Note

The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

⁽¹⁾ Recommended for pass-through holes

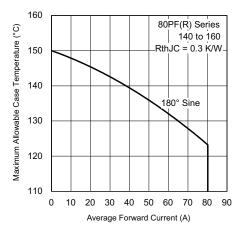


Fig. 1 - Current Ratings Characteristics

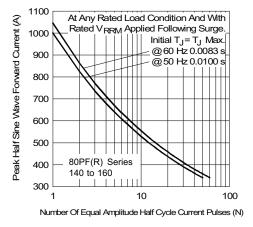


Fig. 2 - Current Ratings Characteristics

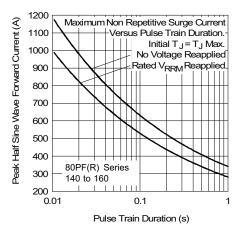


Fig. 3 - Forward Power Loss Characteristics

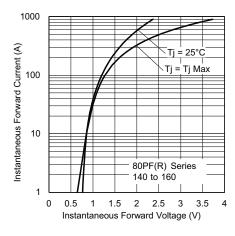


Fig. 4 - Forward Power Loss Characteristics

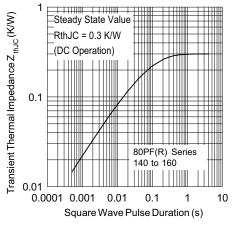


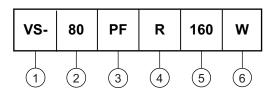
Fig. 5 - Maximum Non-Repetitive Surge Current

VS-80PF(R)...(W) High Voltage Series

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - 80 = standard device

3 - PF = plastic package

None = stud normal polarity (cathode to stud)

• R = stud reverse polarity (anode to stud)

Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

 None = standard terminal (see dimensions for 80PF(R)... - link at the end of datasheet)

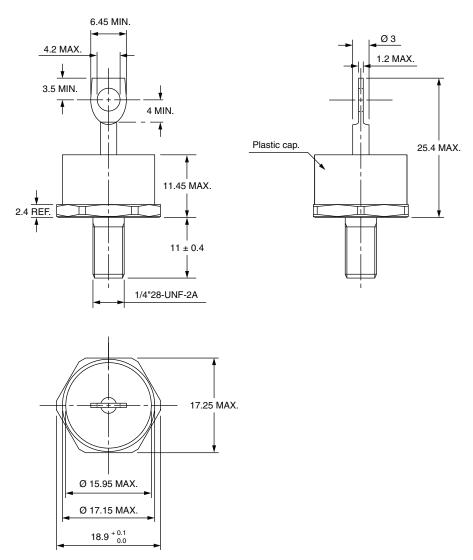
> W = wire terminal (see dimensions for 80PF(R)...W - link at the end of datasheet)

LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95345		



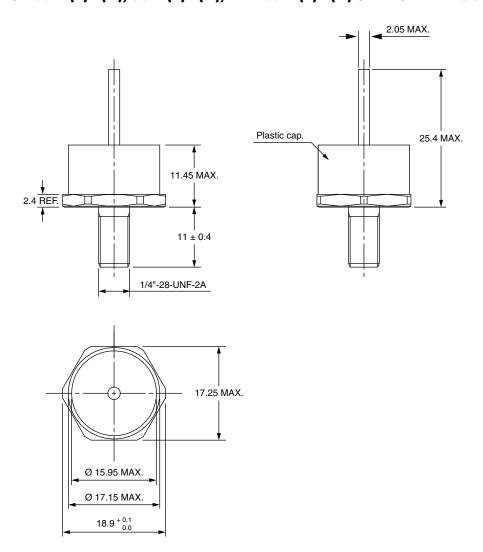
DO-203AB (DO-5) for 50PF(R)...(W), 80PF(R)...(W), and 95PF(R)...(W) Series

DIMENSIONS FOR 80PF(R), 50PF(R), AND 95PF(R) SERIES in millimeters



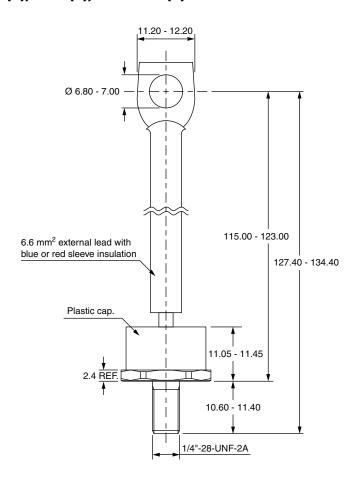


DIMENSIONS FOR 80PF(R)...(W), 50PF(R)...(W), AND 95PF(R)...(W) SERIES in millimeters





DIMENSIONS FOR 52PF(R), 82PF(R), AND 97PF(R) SERIES in millimeters





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